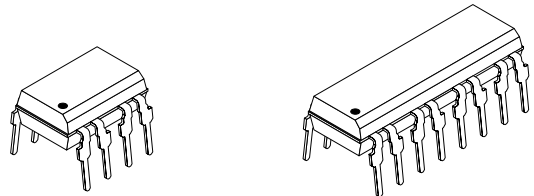


## Multichannel Optocoupler with Phototransistor Output

### Description

The CNY74-2H and CNY74-4H consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in an 8-lead, resp. 16-lead plastic dual inline package.

The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.



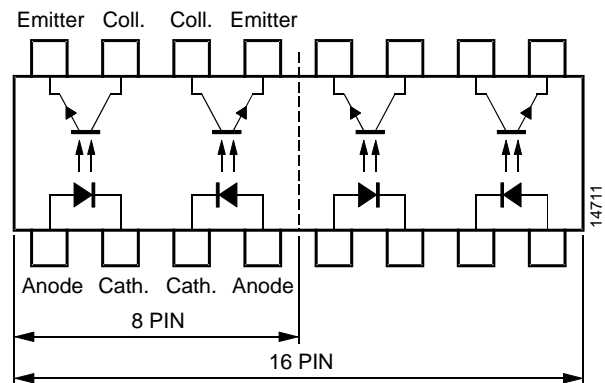
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### Applications

Galvanically separated circuits, non-interacting switches

### Features

- CNY74-2H includes 2 isolater channels
- CNY74-4H includes 4 isolater channels
- Isolation test voltage  $V_{IO} = 5 \text{ kV}$
- Test class 25/100/21 DIN 40 045
- Low coupling capacitance of typical 0.3 pF
- **Current Transfer Ratio (CTR)** of typical 100%
- Low temperature coefficient of CTR
- Wide ambient temperature range
- **Underwriters Laboratory (UL) 1577** recognized, file number E-76222
- **CSA (C-UL) 1577** recognized, file number E-76222 – Double Protection
- Coupling System U



### Order Instruction

Ordering Code	CTR Ranking	Remarks
CNY74-2H	50 to 600%	8 Pin = Dual channel
CNY74-4H	50 to 600%	16 Pin = Quad channel

# CNY74-2H/ CNY74-4H

## Absolute Maximum Ratings

### Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10\mu\text{s}$	$I_{FSM}$	1.5	A
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$

### Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
Peak collector current	$t_p/T = 0.5, t_p \leq 10\text{ ms}$	$I_{CM}$	100	mA
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	150	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$

### Coupler

Parameter	Test Conditions	Symbol	Value	Unit
AC isolation test voltage (RMS)	$t = 1\text{ min}$	$V_{IO}^{1)}$	5	kV
Total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_{tot}$	250	mW
Ambient temperature range		$T_{amb}$	-40 to +100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to +125	$^\circ\text{C}$
Soldering temperature	2 mm from case, $t \leq 10\text{ s}$	$T_{sd}$	260	$^\circ\text{C}$

<sup>1)</sup> Related to standard climate 23/50 DIN 50014

## Electrical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ )

### Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 50 \text{ mA}$	$V_F$		1.25	1.6	V

### Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100 \mu\text{A}$	$V_{ECO}$	7			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	$I_{CEO}$			100	nA

### Coupler

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
DC isolation test voltage	$t = 2 \text{ s}$	$V_{IO}^{1)}$	5			kV
Isolation resistance	$V_{IO} = 1000 \text{ V}$ , 40% relative humidity	$R_{IO}^{1)}$		$10^{12}$		$\Omega$
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$ , $R_L = 100 \Omega$	$f_c$		100		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	$C_k$		0.3		pF

<sup>1)</sup> Related to standard climate 23/50 DIN 50014

### Current Transfer Ratio (CTR)

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
$I_C/I_F$	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$		CTR	0.5	1.0	6.0	
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$		CTR	0.6	1.2		

# CNY74-2H/ CNY74-4H

## Switching Characteristics

Parameter	Test Conditions	Symbol	Typ.	Unit
Delay time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_d$	3.0	$\mu\text{s}$
Rise time		$t_r$	3.0	$\mu\text{s}$
Fall time		$t_f$	4.7	$\mu\text{s}$
Storage time		$t_s$	0.3	$\mu\text{s}$
Turn-on time		$t_{on}$	6.0	$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ (see figure 2)	$t_{off}$	5.0	$\mu\text{s}$
Turn-on time		$t_{on}$	9.0	$\mu\text{s}$
Turn-off time		$t_{off}$	18.0	$\mu\text{s}$

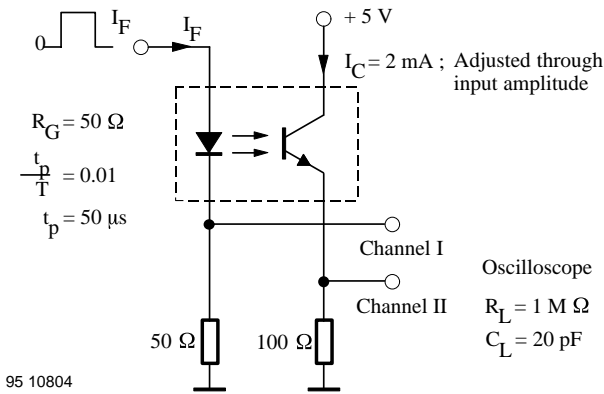


Figure 1. Test circuit, non-saturated operation

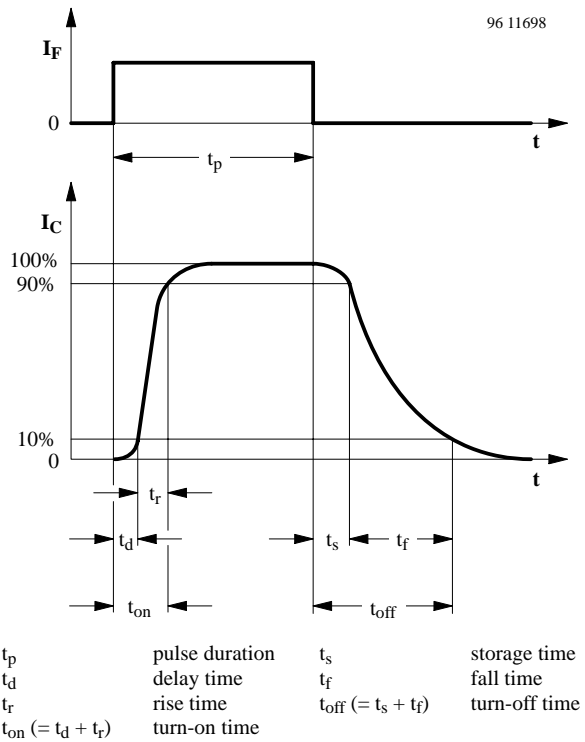


Figure 3. Switching times

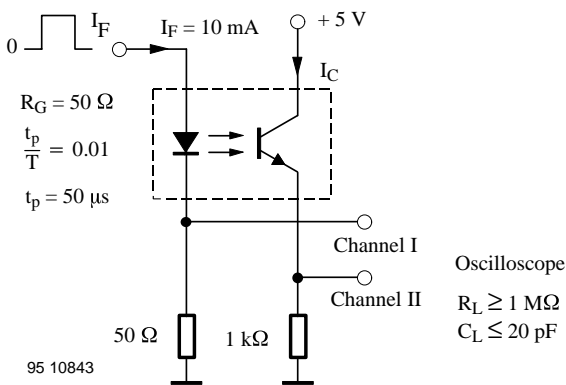


Figure 2. Test circuit, saturated operation

Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

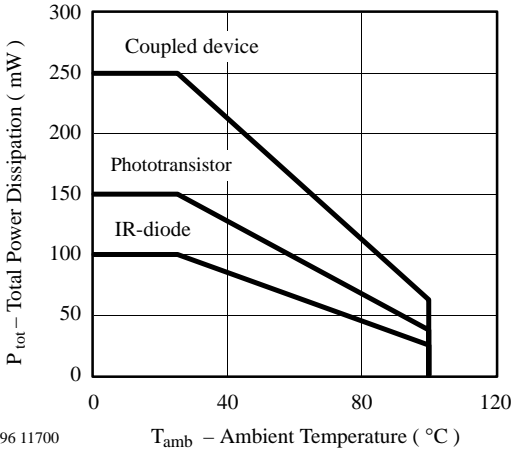


Figure 4. Total Power Dissipation vs. Ambient Temperature

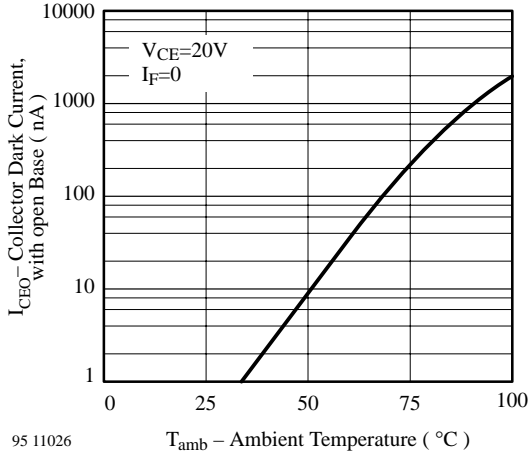


Figure 7. Collector Dark Current vs. Ambient Temperature

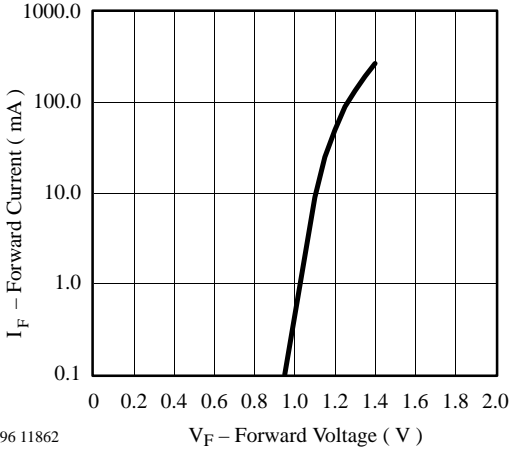


Figure 5. Forward Current vs. Forward Voltage

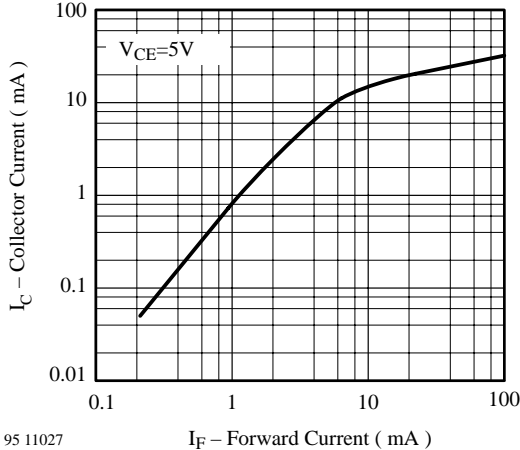


Figure 8. Collector Current vs. Forward Current

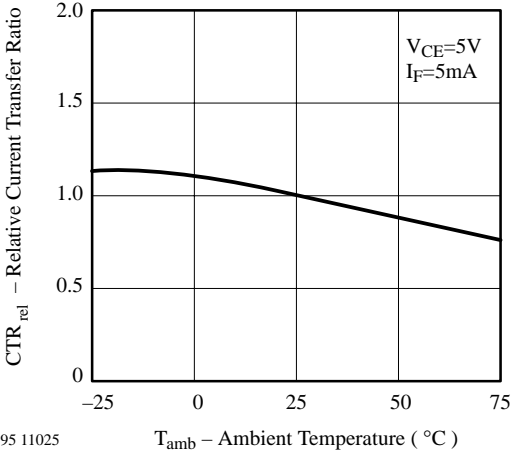


Figure 6. Relative Current Transfer Ratio vs. Ambient Temperature

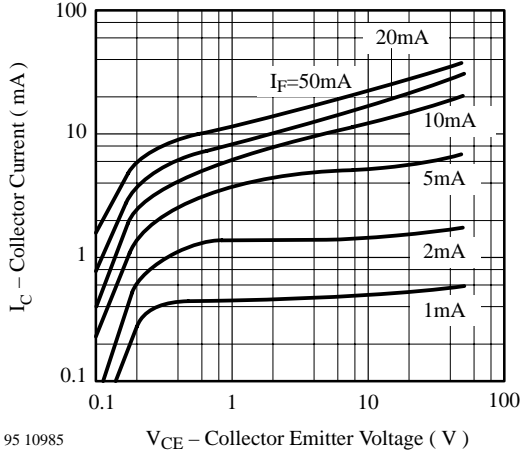


Figure 9. Collector Current vs. Collector Emitter Voltage

# CNY74-2H/ CNY74-4H

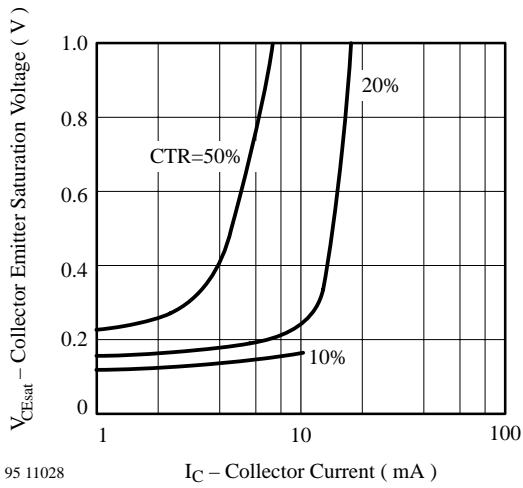


Figure 10. Collector Emitter Saturation Voltage vs. Collector Current

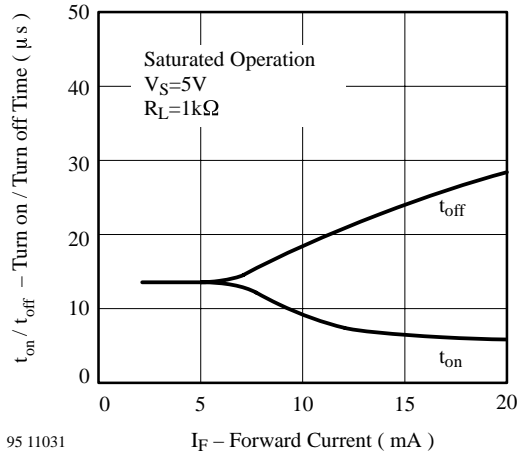


Figure 12. Turn on / off Time vs. Forward Current

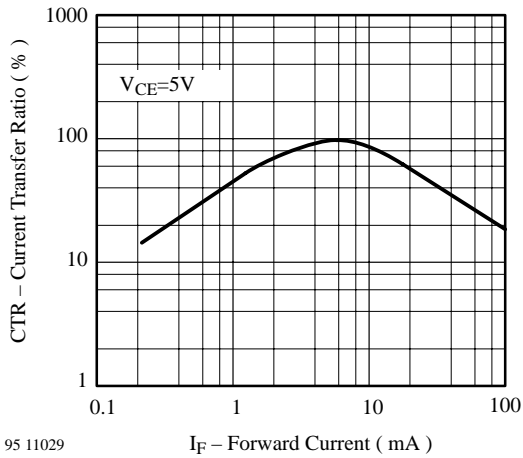


Figure 11. Current Transfer Ratio vs. Forward Current

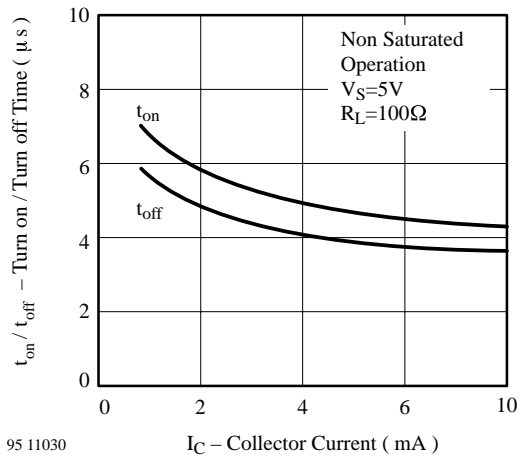
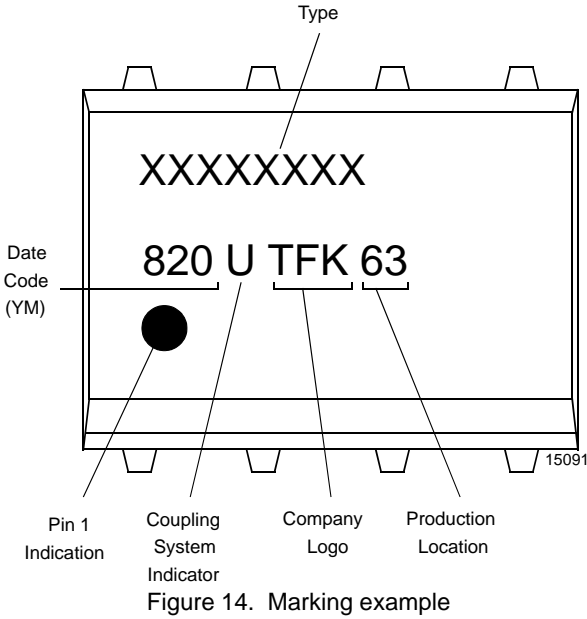
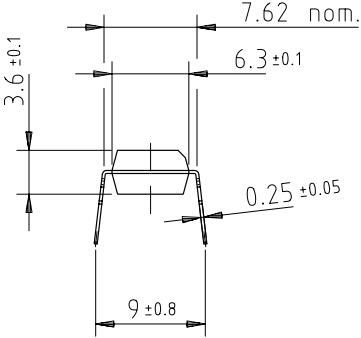
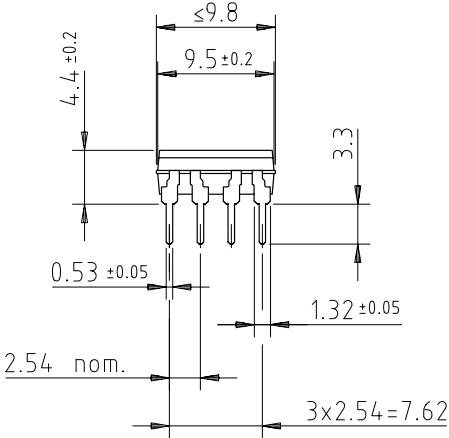


Figure 13. Turn on / off Time vs. Collector Current

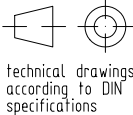
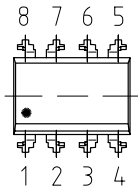


## Dimensions of CNY74-2 in mm



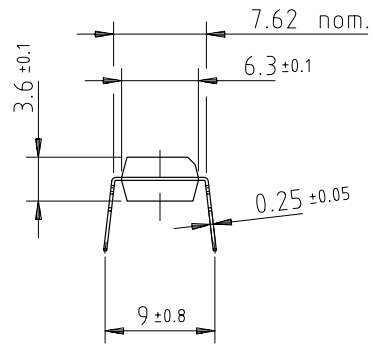
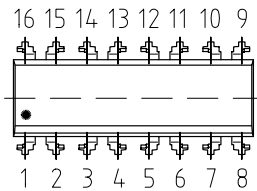
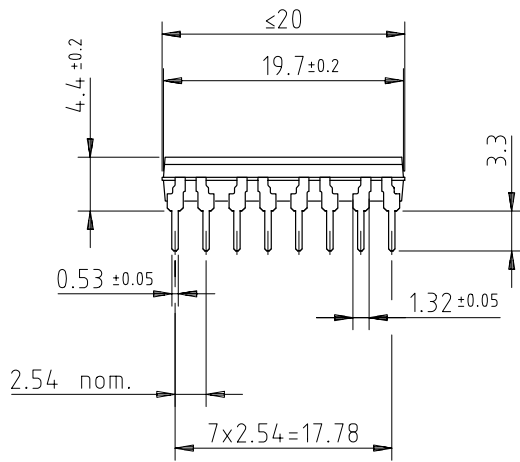
weight: ca. 0.55 g  
 creepage distance:  $\geq 6 \text{ mm}$   
 air path:  $\geq 6 \text{ mm}$

after mounting on PC board



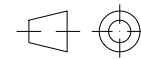
# CNY74-2H/ CNY74-4H

## Dimensions of CNY74-4 in mm



weight: ca. 1.0 g  
creepage distance:  $\geq 6 \text{ mm}$   
air path:  $\geq 6 \text{ mm}$

after mounting on PC board



technical drawings  
according to DIN  
specifications

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